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State of Art Review of Various Control Methods for Cascade H-Bridge 5-Level Inverter to Mitigate Harmonics

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Abstract: The modified Space Vector Pulse Width Modulation (Modified SVPWM) with triangular type multi carriers is proposed to control the switches for Cascade H-Bridge (CHB) 5-level inverter. The phase shift and level shift carriers are used in both Sinusoidal and modified SVPWM methods. The comparative harmonic analysis of modified SVPWM and sinusoidal PWM (SPWM) for CHB 5-level with various modulation indices is validated through simulation results.

Keywords: Cascade H-bridge; Phase shift; PD; POD; APOD; SPWM; Modified SVPWM and THD.

I. INTRODUCTION

The higher level inverters are an important role in various applications. The CHB inverters are having more advantages when compare to all other multilevel inverters, because of its modularity. Various advantages and applications include motor drive; transmission and distribution are presented in [1]. The CHB inverter performance is high compared to all other multilevel inverter [2].

Various gate control methods are: phase shift and level shift methods are used to control the gate pulse of an IGBT device in CHB 5-level inverter [4]. The level shift PWM is preferred due to fewer harmonics compared to phase shift carrier gate control method [5]. The harmonic reduction concept for CHB inverters is presented in [6]. In this proposed work, the CHB 5-level inverter load voltage is discussed for different modulation methodologies. The RL load is considered for performance evaluation of both level and phase shift carrier based gate control methodologies.

II. CHB 5-LEVEL INVERTER

The schematic diagram of CHB 5-level inverter and m-level inverter is illustrated in Fig.1 and Fig.2. An equivalent 5-level load voltage is presented in Fig.3, which is $v_{an} = v_{a1} + v_{a2} + v_{a3} + v_{a4}$. The four switches of one H-Bridge is denoted as S_{a1} , S_{a2} , S_{a3} , and S_{a4} . Switching on S_{1} and S_{4} gives $V_{a4} = +V_{dc}$, likewise switching on S_{2} and switch S_{3}

gives $V_{a4} = -V_{dc}$. By switching off all IGBTs yields Va4=0. If the V_{dcn} is the 'n' number of dc supplies, the RL load line-ground voltage level is $m = V_{dcn} + 1$. Therefore, four DC supplies are required to operate a 5-level CHB inverter. Harmonics are reduced at different inverter level of waveform due to on/off control of an IGBT device angles during conduction.

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III. ADVANCED PWM TECHNIQUES

Various types of gate control techniques and the carriers are shown in Fig. 4 & Fig.5. The triangular carriers are chosen on the basis of the formula m-1, i.e 5-1=4 for the gate pulses of 5-level CHB inverter. Phase Disposition (PD) carriers are having the same in amplitude, frequency, and phases, but they are differ in DC offset to inhabit adjacent bands as shown in Fig 6, and Fig.7. Phase Opposition Disposition (POD) Carriers are having the same in magnitude and frequency but they are differing in phase and DC offset in Fig.8 & Fig.9. Alternative Phase Opposition Disposition (APOD) carriers are having the same magnitude and frequency but they are be different in their DC offset and phases as shown in Fig.10 and Fig.11.

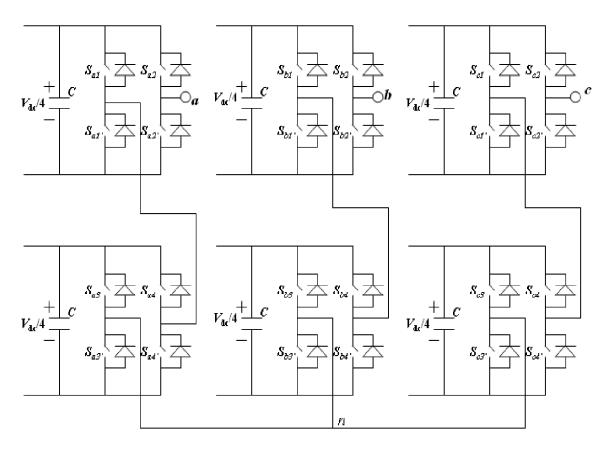


Figure 1: 3-phase 3-leg 5-level CHB inverter [7], [8]

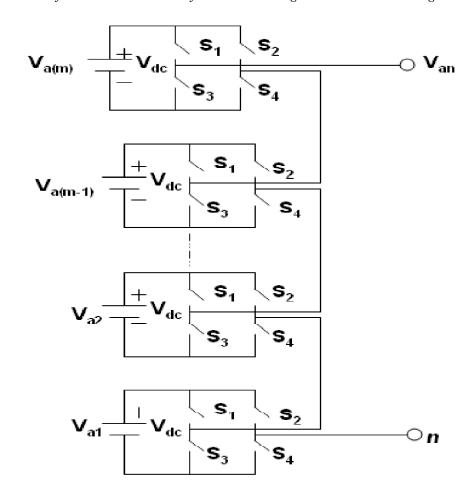


Figure 2: CHB m-level inverter [7], [8]

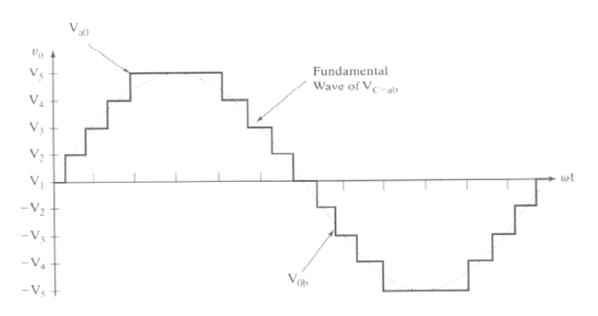


Figure 3: Output waveform of 5-level inverter [7], [8]

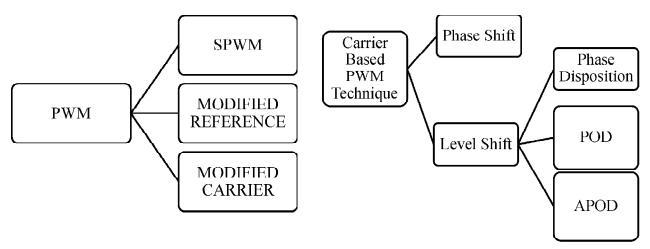


Figure 4: Types of PWM Techniques

Figure 5: Types of Carriers

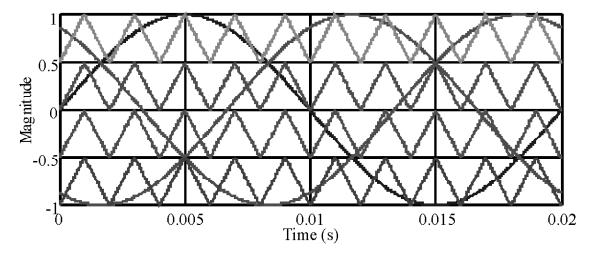


Figure 6: PD based gate pulse using SPWM

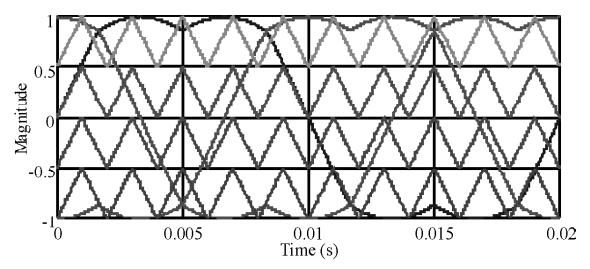


Figure 7: PD based gate pulse using modified SVPWM

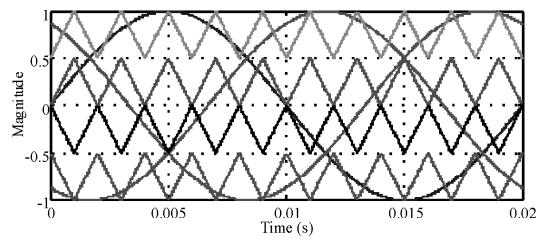


Figure 8: POD based gate pulse using SPWM

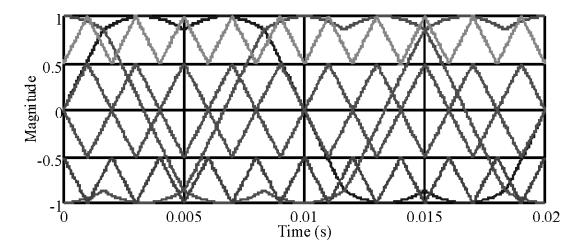


Figure 9: POD based gate pulse using modified SVPWM

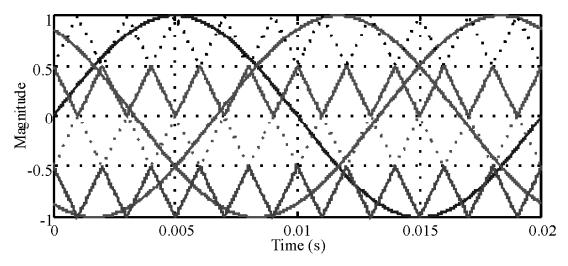


Figure 10: APOD based gate pulse using SPWM

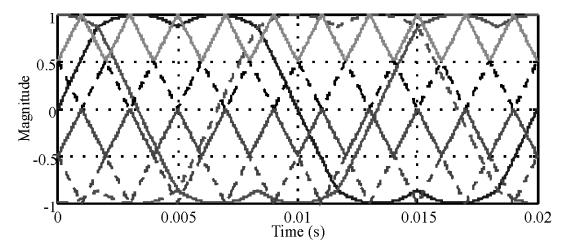


Figure 11: APOD based gate pulse using modified SVPWM

IV. SIMULATION RESULT ANALYSIS

4.1. SPWM

In this Section, level shift and phase shift carriers is considered for result analysis. RL load parameters: are $R=50\Omega$ and L=110mH. The DC voltage is 400V is applied. The switching frequency is 10 kHz.

(A) Phase Shift Carriers

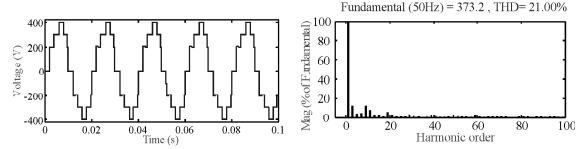


Figure 12: Line-Line load Voltage and FFT spectrum Using phase shift carriers

(B) Level Shift Carriers

Fig.12 is the Line-Line load Voltage and FFT spectrum using phase shift carriers with total harmonic distortion is 21.00%. Fig.13, Fig.14 and Fig.15 is the Line-Line load Voltage and FFT spectrum using APOD, POD and PD triangular carriers with total harmonic distortion is 14.54%, 11.26% and 6.07% respectively using SPWM. The simulation results are presented in Table I.

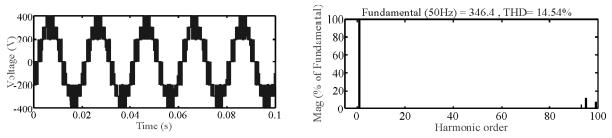
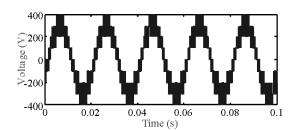


Figure 13: Line-Line load Voltage and FFT spectrum Using APOD



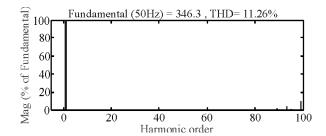
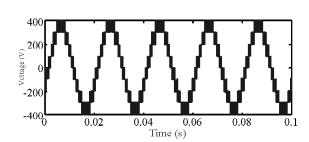


Figure 14: Line-Line load Voltage and FFT spectrum Using POD



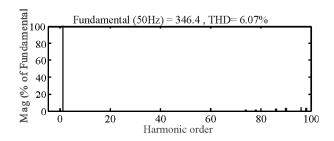
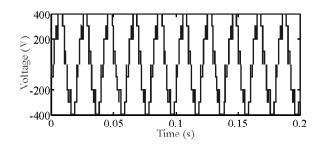


Fig.15. Line-Line load Voltage and FFT spectrum Using PD

Table I
The %THD comparison of load voltage for SPWM

Modulation index (1	M)	Type of Carriers			
	Phase Shift	Level shift			
		PD	POD	APOD	
M=1	21.00	6.07	11.26	14.54	
M=0.9	26.78	5.29	17.73	17.01	
M=0.8	33.48	8.31	22.06	16.97	
M=0.7	29.44	8.46	22.86	12.45	

4.2. Modified SVPWM



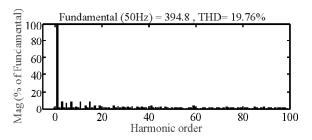
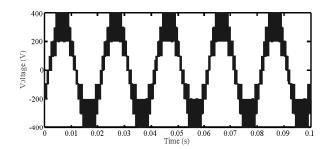


Figure 16: Line-Line load Voltage and FFT spectrum Using phase shift carriers

Fig.16 is Line-Line load Voltage and FFT spectrum using phase shift carriers with total harmonic distortion is 19.76%. Fig.17, Fig.18 and Fig.19 is Line-Line load Voltage and FFT spectrum using POD, APOD, and PD triangular carriers with total harmonic distortion is 9.06%, 9.02% and 4.65% respectively using modified SVPWM

technique. The simulation results are presented in Table II. The comparative illustration of SPWM and Modified SVPWM is shown in Fig. 20.



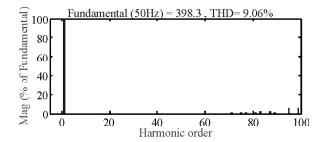
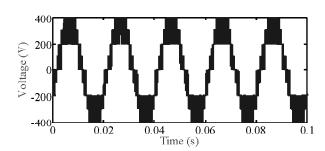


Figure 17: Line-Line load Voltage and FFT spectrum Using POD



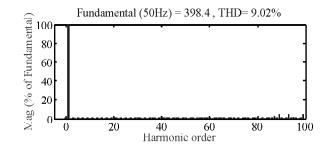
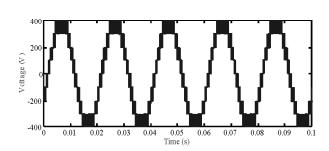


Figure 18: Line-Line load Voltage and FFT spectrum Using APOD



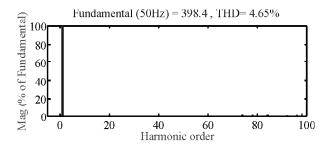


Figure 19: Line-Line load Voltage and FFT spectrum Using PD

Table II						
%THD comparison of load voltage for modified SVPWM						

Modulation index (M)	Type of Carriers				
	Phase Shift	Level shift			
		PD	POD	APOD	
M=1	19.76	4.65	9.06	9.02	
M=0.9	27.25	3.46	15.66	15.62	
M=0.8	32.41	5.57	21.01	21.03	
M=0.7	36.65	5.23	21.36	21.37	

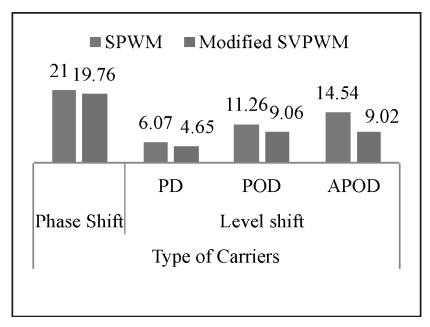


Figure 20: An illustration of Total Harmonic Distortion using SPWM and Modified SVPWM

V. CONCLUSION

In this paper, various Carrier-Based PWM techniques of PD, POD and APOD are analyzed. The simulation result analysis for line-line load voltage with harmonic spectrum is discussed. 5-level CHB inverter of modified reference with triangular carrier PWM technique have good FFT spectrum with THD (4.65%) when compared with modified PSPWM (19.76%).

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